

Replaces February 2000 version, DS5267-1.3

#### **APPLICATIONS**

- Pulse Power
- Crowbars
- Ignitron Replacement

#### **FEATURES**

- Double Side Cooling
- Fast Turn-on
- Low Turn-on Losses

#### **VOLTAGE RATINGS**

Type Number	Repetitive Peak Voltages V <sub>DRM</sub> /V <sub>RRM</sub> V	Conditions
PT60QHx45	4500/16	$T_{vj} = 0^{\circ} \text{ to } 125^{\circ}\text{C},$ $I_{DRM} = I_{RRM} = 100\text{mA},$ $V_{DRM}, V_{RRM} t_{p} = 10\text{ms}$

Lower voltage grades available.

### **CURRENT RATINGS**

Symbol	Parameter	Conditions	Max.	Units
Double Sid	e Cooled			
I <sub>T(AV)</sub>	Mean on-state current	Half wave resistive load, $T_{case} = 80^{\circ}C$	1000	А
I <sub>T(RMS)</sub>	RMS value	$T_{case} = 80^{\circ}C$	1570	А

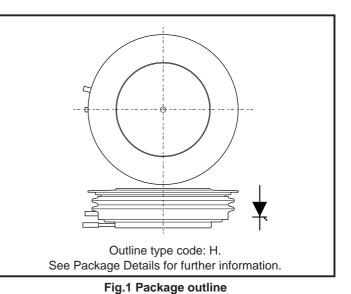
# PT60QHx45

# **Pulse Power Thyristor Switch**

Preliminary Information DS5267-1.4 April 2000

#### **KEY PARAMETERS**

V <sub>DRM</sub>	4500V
	1000A
I <sub>TSM</sub>	22500A
dl/dt	<b>10,000Α/</b> μs



## PT60QHx45

## SURGE RATINGS

Symbol	Parameter	Conditions	Max.	Units
I <sub>TSM</sub>	Surge (non-repetitive) on-state current	10ms half sine; T <sub>case</sub> = 125°C	17.8	kA
l <sup>2</sup> t	I <sup>2</sup> t for fusing	$V_{R} = 50\% V_{RRM} - 1/4 \text{ sine}$	15.8 x 10 <sup>6</sup>	A²s
I <sub>TSM</sub>	Surge (non-repetitive) on-state current	10ms half sine; T <sub>case</sub> = 125°C	22.5	kA
l²t	I <sup>2</sup> t for fusing	V <sub>R</sub> = 0	2.52 x 10 <sup>6</sup>	A²s

## THERMAL AND MECHANICAL DATA

Symbol	Parameter	Conditions		Min.	Max.	Units
R <sub>th(j-c)</sub>	Thermal resistance - junction to case	Double side cooled	dc	-	0.013	°C/W
R <sub>th(c-h)</sub>	Thermal resistance - case to heatsink	Clamping force 19.5kN with mounting compound	Double side	-	0.003	°C/W
T Vistual institu	Virtual junction temporature	On-state (conducting)		-	135	°C
T <sub>vj</sub> Virtual junction temperature		Reverse (blocking)		-	125	°C
T <sub>stg</sub>	Storage temperature range			-55	125	°C
-	Clamping force			18	22	kN

## **DYNAMIC CHARACTERISTICS**

Symbol	Parameter	Conditions		Тур.	Max.	Units
I <sub>RRM</sub> /I <sub>DRM</sub>	Peak reverse and off-state current	At $V_{RRM}/V_{DRM}$ , $T_{case} = 125^{\circ}C$		-	100	mA
dV/dt	Maximum linear rate of rise of off-state voltage	To 67% $V_{DRM} T_j = 125^{\circ}C. R_{gk} \le 1.5\Omega$		-	175	V/µs
dl/dt	Rate of rise of on-state current	From 67% V <sub>DRM</sub> to 40kA Gate source 60A $t_r = 1.5\mu s$ to 1A, $T_j = 25^{\circ}C$	Non-repetitive	-	10000	A/μs
V <sub>T(TO)</sub>	Threshold voltage	At $T_{vj} = 125^{\circ}C$		-	1.5	V
r <sub>T</sub>	On-state slope resistance	At $T_{vj} = 125^{\circ}C$		-	0.67	mΩ

# GATE TRIGGER CHARACTERISTICS AND RATINGS

Symbol	Parameter	Conditions	Тур.	Max.	Units
V <sub>gt</sub>	Gate trigger voltage	$V_{\text{DRM}} = 5V, T_{\text{case}} = 25^{\circ}\text{C}$	-	1.0	V
Ι <sub>GT</sub>	Gate trigger current	$V_{DRM} = 5V, T_{case} = 25^{\circ}C$	-	3	А

# PT60QHx45

## **ORDERING INFORMATION**

- PT Pulse Power Thyristor
- 40Q Device type
- P Package outline type code
- x lead length (see table, right)
- 45 Voltage x100

Lead length (x)				
0	No lead			
С	8"	200mm		
D	10"	250mm		
E	12"	300mm		
F	16"	400mm		
G	18"	450mm		
Н	20"	500mm		
J	24"	600mm		
K	30"	750mm		
L	40"	1000mm		

## CURVES

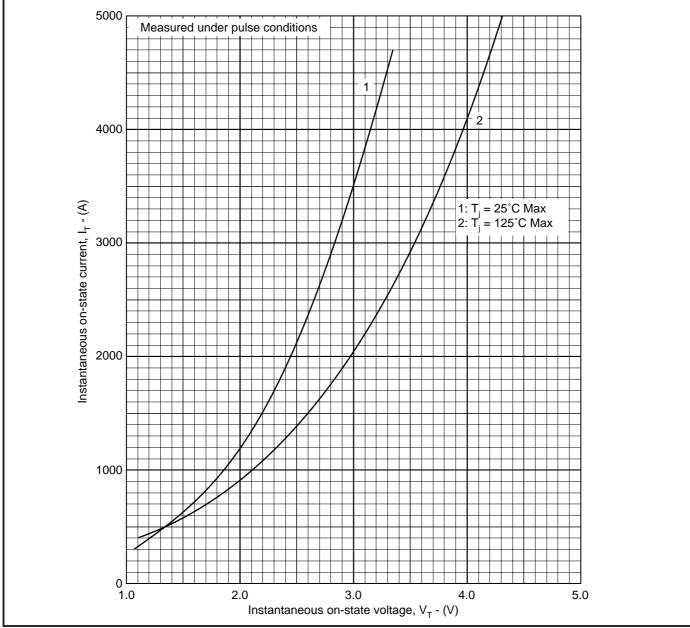


Fig.2 Maximum (limit) on-state characteristics

## PT60QHx45

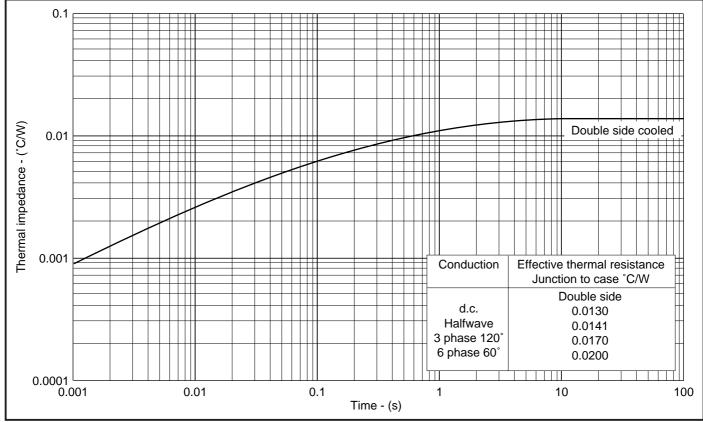
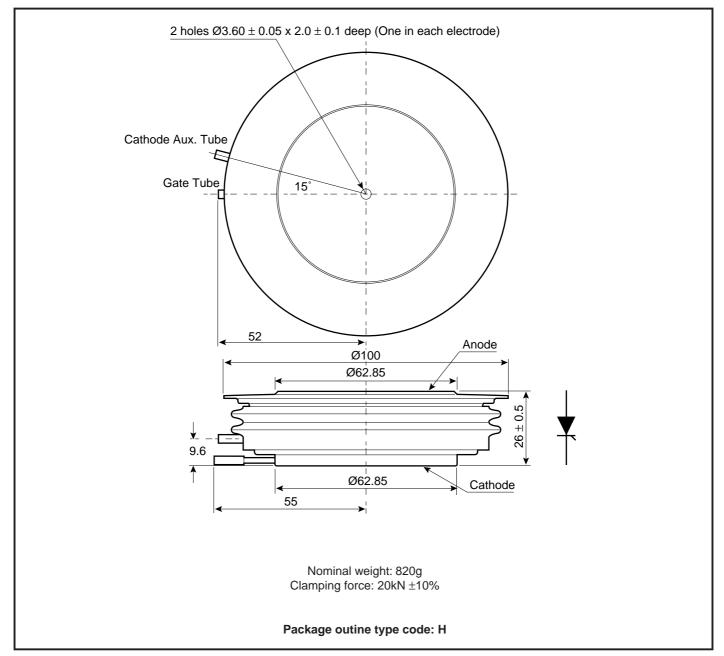


Fig.3 Maximum (limit) transient thermal impedance - junction to case

#### **Package Details**

For further package information, please contact your local Customer Service Centre. All dimensions in mm, unless stated otherwise. DO NOT SCALE.





#### POWER ASSEMBLY CAPABILITY

The Power Assembly group was set up to provide a support service for those customers requiring more than the basic semiconductor, and has developed a flexible range of heatsink and clamping systems in line with advances in device voltages and current capability of our semiconductors.

We offer an extensive range of air and liquid cooled assemblies covering the full range of circuit designs in general use today. The Assembly group offers high quality engineering support dedicated to designing new units to satisfy the growing needs of our customers.

Using the latest CAD methods our team of design and applications engineers aim to provide the Power Assembly Complete Solution (PACs).

#### HEATSINKS

The Power Assembly group has its own proprietary range of extruded aluminium heatsinks which have been designed to optimise the performance of Dynex semiconductors. Data with respect to air natural, forced air and liquid cooling (with flow rates) is available on request.

For further information on device clamps, heatsinks and assemblies, please contact your nearest sales representative or Customer Services.



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Preliminary Information: The product is in design and development. The datasheet represents the product as it is understood but details may change.

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